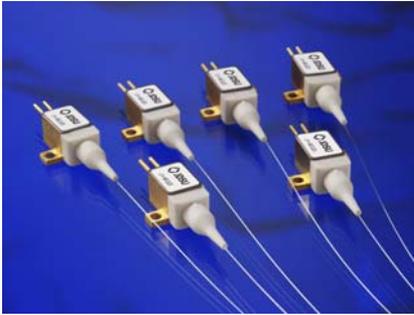


# High-Power 10 W 976 nm Fiber-Coupled Diode Laser

## 6398-L4t Series

**Key Features**

- 976±3 nm wavelength
- 10 W output power
- High reliability
- 105 μm aperture
- 0.22 or 0.15 NA
- Isolated electrical contacts

**Application**

- Fiber laser pumping

The JDSU L4t Series fiber-coupled diode laser expands our L4 platform by offering a tighter wavelength range specification of 976 nm for the fiber laser pumping market.

By accurately controlling the wavelength of the epitaxial structure during growth, the L4t is specified at ±3 nm around 976 nm for pumping fiber lasers in this narrow pump absorption bandwidth.

Our 6398-L4t series diode lasers offer 10 W of power from a 105 μm fiber. In addition, the L4t multimode pump modules take advantage of the existing global JDSU manufacturing infrastructure to offer both high brightness and a small footprint with consistent high reliability in a cost-effective solution.

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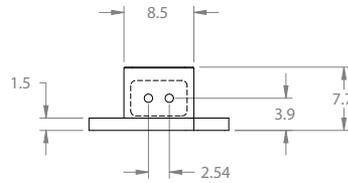
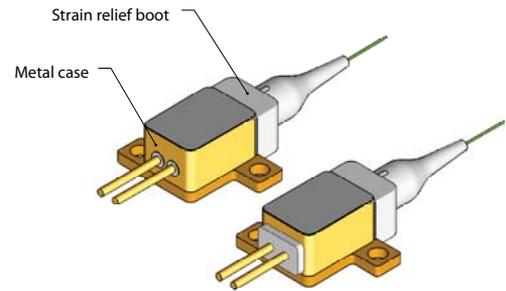
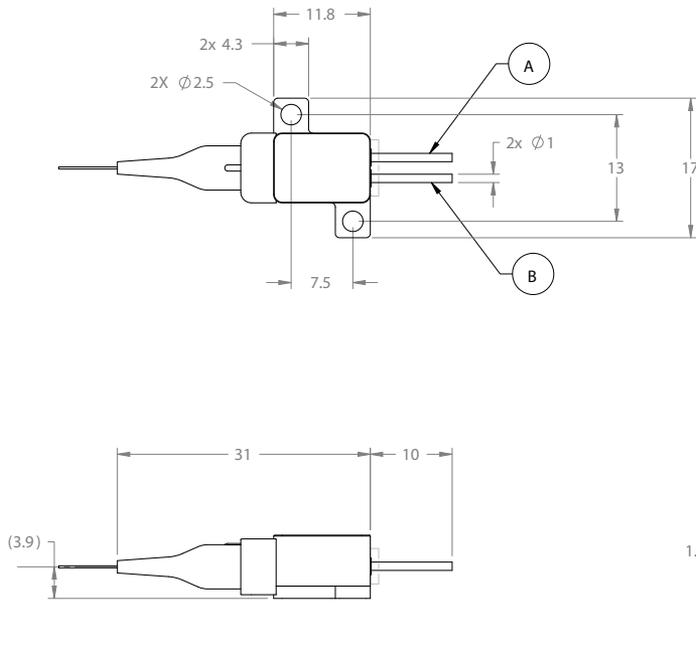
**Dimensions Diagram**

(Specifications in mm unless otherwise noted.)

Standard Tolerances

mm: x.x = ±0.5

x.xx = ±0.25



**Pinout**

Pin	Description
A	Laser cathode (-)
B	Laser anode (+)

## 3

Specifications for 0.22NA<sup>1</sup>

Parameter	Symbol	Minimum	Typical	Maximum
<b>Laser Characteristics</b>				
CW output power	$P_o$	-	-	10 W
Mean wavelength <sup>2</sup>	$\lambda_p$ 976 nm	973 nm	976 nm	979 nm
Spectral width (90% integrated power)	$\Delta\lambda$	-	3 nm	6 nm
Slope efficiency	$\eta_D$ 975 nm	-	0.90 W/A	-
Conversion efficiency	$\eta$	-	48%	-
Threshold current	$I_{th}$	-	600 mA	850 mA
Operating current (BOL)	$I_{op}$ 975 nm	-	11.8 A	13.0 A
Forward voltage	$V_f$	-	1.81 V	2.0 V
Series resistance	$R_s$	-	0.04 $\Omega$	-
Recommended case temperature	$T_c$	20°C	25°C	40°C
Wavelength tuning vs. temperature <sup>3</sup>	$\Delta\lambda/\Delta T$	-	0.35 nm/°C	-
Wavelength tuning vs. output power	$\Delta\lambda/\Delta P$	-	1.0 nm/W	-
<b>Fiber Characteristics</b>				
Fiber core diameter	$d_c$	-	105 $\mu\text{m}$	-
Fiber numerical aperture	NA	0.20	0.22	0.24
Fiber cladding	$d_{cl}$	-	125 $\mu\text{m}$	-
Fiber buffer	$d_b$	-	250 $\mu\text{m}$	-
Fiber length	$l_f$	0.9 m	1 m	-

1. All performance data measured at 10 W, 25°C, beginning of Life (BOL).

2. Weighted average "center of mass" spectral point at 25°C at  $P_o$

3. Change in  $\Delta\lambda$  mean with case temperature over  $T_{op}$

## 4

Specification for 0.15 NA<sup>1</sup>

Parameter	Symbol	Minimum	Typical	Maximum
<b>Laser Characteristics</b>				
CW output power	$P_o$	-	-	10 W
Mean wavelength <sup>2</sup>	$\lambda_p$ 976 nm	973 nm	976 nm	979 nm
Spectral width (90% integrated power)	$\Delta\lambda$	-	3 nm	6 nm
Slope efficiency	$\eta_D$ 975 nm	-	0.90 W/A	-
Conversion efficiency	$\eta$	-	46%	-
Threshold current	$I_{th}$	-	600 mA	850 mA
Operating current	$I_{op}$ 975 nm	-	12.3 A	13.5 A
Forward voltage	$V_f$	-	1.81 V	2.0 V
Series resistance	$R_s$	-	0.04 $\Omega$	-
Recommended case temperature	$T_c$	20°C	25°C	40°C
Wavelength tuning vs. temperature <sup>3</sup>	$\Delta\lambda/\Delta T$	-	0.35 nm/°C	-
Wavelength tuning vs. output power	$\Delta\lambda/\Delta P$	-	1.0 nm/W	-
<b>Fiber Characteristics</b>				
Fiber core diameter	$d_c$	-	105 $\mu\text{m}$	-
Fiber numerical aperture	NA	0.135	0.15	0.165
Fiber cladding	$d_d$	-	125 $\mu\text{m}$	-
Fiber buffer	$d_b$	-	250 $\mu\text{m}$	-
Fiber length	$l_f$	0.9 m	1 m	-

1. All performance data measured at 10 W, 25°C, beginning of Life (BOL).

2. Weighted average "center of mass" spectral point at 25°C at  $P_o$

3. Change in  $\Delta\lambda$  mean with case temperature over  $T_{op}$

## 5

**Absolute Maximum Ratings**

Parameter	Symbol	Minimum	Typical	Maximum
Operating current	$I_{op}$	-	-	14 A
Reverse voltage	$V_{rvs}$	-	-	2.0 V
Case operating temperature <sup>1</sup>	$T_{op}$	15°C	-	50°C
Storage temperature <sup>2</sup>	$T_{stg}$	-30°C	-	70°C
Lead soldering temperature, 10 s max	$T_{ls}$	-	-	300°C
Relative humidity, non-condensing, ambient < 45°C	RH	-	-	85%
Electrostatic discharge (ESD) <sup>3</sup>	$V_{esd}$	-	-	500 V
Fiber bend radius (long term deployment) <sup>4</sup>		30 mm	-	-
Fiber axial pull force, 15 s		-	-	5 N
Fiber side pull force, 15 s		-	-	2.5 N

1. Noncondensing, maximum

2. Noncondensing, 2000 hours

3. C = 100 pF, R = 1.5 kΩ, human body model, shown to be not damaging to its LI characteristics or its reliability, I-V curves may change in this ESD environment

4. Minimum bend radius of 30 mm is for long term mechanical fiber reliability; however for 0.15 NA some optical loss may occur and a minimum bend radius of 45 mm is recommended for layout with multiple fiber coils.

**Configurations**

Product Code	Wavelength Range	Fiber NA
L4-9897603-100B	973–979nm	0.22
L4-9897603-100C	973–979nm	0.15

**Ordering Information**

For more information on this or other products and their availability, please contact your local JDSU account manager or JDSU directly at 1-800-498-JDSU (5378) in North America and +800-5378-JDSU worldwide or via e-mail at [customer.service@jdsu.com](mailto:customer.service@jdsu.com).

**Sample: L4-9897603-100B**

**User Safety**
**Safety and Operating Considerations**

The laser light emitted from this diode laser is invisible and may be harmful to the human eye. Avoid looking directly into the diode laser or into the collimated beam along its optical axis when the device is in operation.

**CAUTION: THE USE OF OPTICAL INSTRUMENTS WITH THIS PRODUCT WILL INCREASE EYE HAZARD.**

Operating the diode laser outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum peak optical power cannot be exceeded. CW diode lasers may be damaged by excessive drive current or switching transients. When power supplies are used, the diode laser should be connected with the main power on and the output voltage at zero. The current should be increased slowly while the diode laser output power and the drive current are monitored.

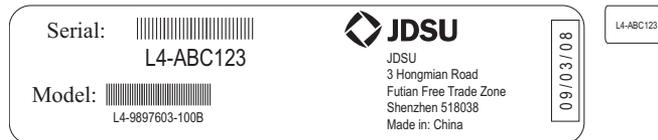
Device degradation accelerates with increased temperature, and therefore careful attention to minimizing the case temperature is advised. For example, life expectancy will decrease by a factor of four if the case is operated at 50 °C rather than 25 °C.

A proper heatsink for the diode laser on a thermal radiator will greatly enhance laser life. Firmly mount the laser on a radiator with a thermal impedance of less than 0.5 °C/W for increased reliability.

ESD PROTECTION—Electrostatic discharge is the primary cause of unexpected diode laser failure. Take extreme precaution to prevent ESD. Use wrist straps, grounded work surfaces, and rigorous antistatic techniques when handling diode lasers.

**Labeling**
**21 CFR 1040.10 Compliance**

Because of the small size of these devices, each of the labels shown is attached to the individual shipping container. They are illustrated here to comply with 21 CFR 1040.10 as applicable under the Radiation Control for Health and Safety Act of 1968.

**Serial Number Identification Label**

**Output Power Danger Label**
